



**Product data sheet** 

## 1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a TO220 plastic package intended for use in applications requiring good bidirectional blocking voltage capability and high thermal cycling performance.

## 2. Features and benefits

- · Good bidirectional blocking voltage capability
- High thermal cycling performance

## 3. Applications

- Ignition circuits
- Motor control
- Protection circuits
- Voltage regulation

## 4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	-	800	V
$V_{RRM}$	repetitive peak reverse voltage		-	-	800	V
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5	-	-	100	А
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	-	-	110	А
T <sub>j</sub>	junction temperature		-	-	125	°C
$I_{T(AV)}$	average on-state current	half sine wave; T <sub>mb</sub> ≤ 109 °C; <u>Fig. 1</u>	-	-	7.5	A
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 109 °C; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	-	12	А
Static ch	aracteristics	· ·				
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	2	15	mA
Dynamic	characteristics	· ·				
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$      V_{\text{DM}} = 536 \text{ V};  \text{T}_{\text{j}} = 125 ^{\circ}\text{C};  \text{R}_{\text{GK}} = 100  \Omega; \\       (\text{V}_{\text{DM}} = 67\% \text{ of } \text{V}_{\text{DRM}}); \text{ exponential} \\       waveform;  \text{Fig. 12} $	200	1000	-	V/µs
				1	1	

# 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	
2	A	anode	1 204	А Ӈ К
3	G	gate		G sym037
mb	A	mounting base; connected to anode		

# 6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	name		method	quantity	version	issue date		
BT151-800C	TO220	BT151-800C,127	Tube	50	SOT78	13-Jun-2008		

## 7. Marking

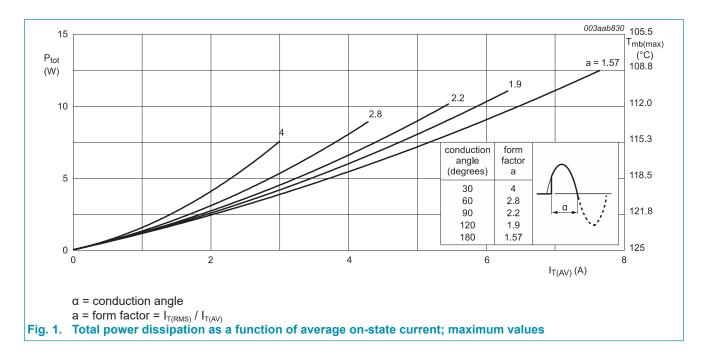
# Table 4. Marking codes Type number Marking codes Assembly factory: d Assembly factory: A BT151-800C BT151 BT151 B00C B00C B00C PJdxxxx xx PJAxxxx xx

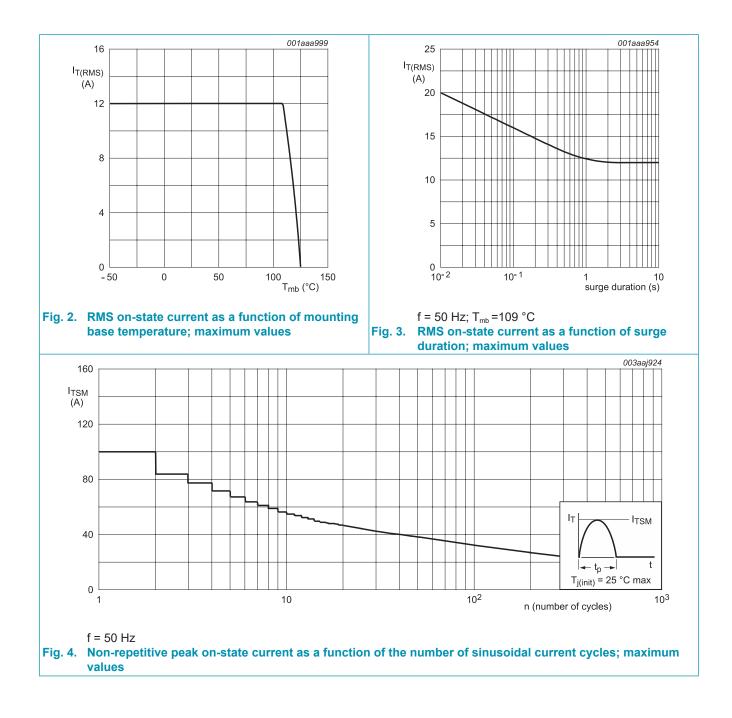
# 8. Limiting values

## Table 5. Limiting values

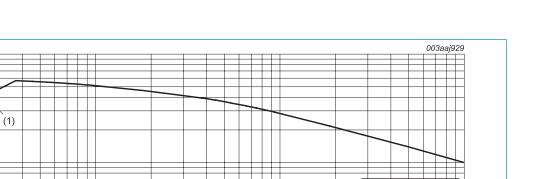
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DRM}$	repetitive peak off-state voltage		-	800	V
$V_{RRM}$	repetitive peak reverse voltage		-	800	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; $T_{mb} \le 109 \text{ °C}$ ; Fig. 1	-	7.5	А
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; $T_{mb} \le 109 \text{ °C}$ ; Fig. 2; Fig. 3	-	12	А
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5	-	100	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	-	110	А
l <sup>2</sup> t	l <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN	-	50	A <sup>2</sup> s
dl <sub>T</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 30 mA	-	50	A/µs
I <sub>GM</sub>	peak gate current		-	2	А
V <sub>RGM</sub>	peak reverse gate voltage		-	5	V
$P_{GM}$	peak gate power		-	5	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	150	°C
T <sub>i</sub>	junction temperature		-	125	°C



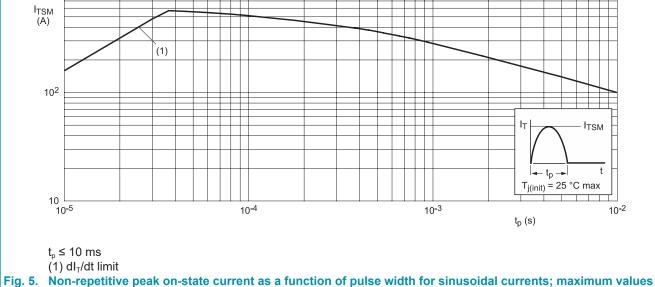


10<sup>3</sup>



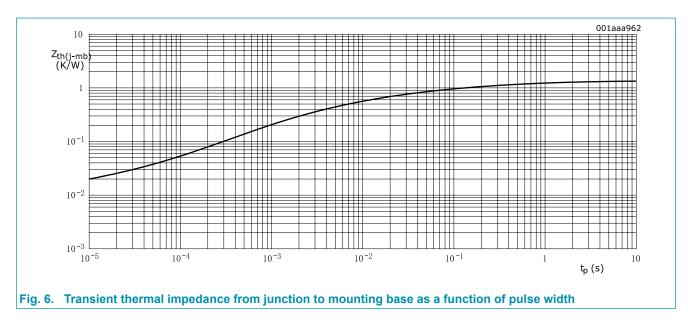
BT151-800C

SCR



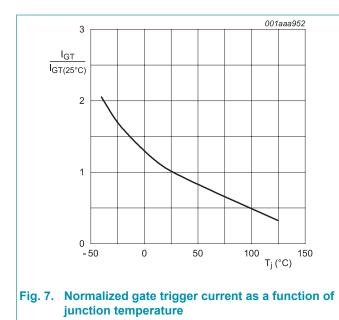
## 9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	-	1.3	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W



# **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
I <sub>GT</sub>	gate trigger current	$V_{\rm D}$ = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	2	15	mA
I <sub>L</sub>	latching current	$V_{\rm D}$ = 12 V; I <sub>G</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 8	-	10	40	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	7	20	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 23 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.44	1.75	V
$V_{\text{GT}}$	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	0.6	1.5	V
		V <sub>D</sub> = 500V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C	0.25	0.4	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 500 V; T <sub>j</sub> = 125 °C	-	0.1	0.5	mA
I <sub>R</sub>	reverse current	V <sub>R</sub> = 500 V; T <sub>j</sub> = 125 °C	-	0.1	0.5	mA
Dynamic	characteristics	-			1	
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 536 V; T <sub>j</sub> = 125 °C; R <sub>GK</sub> = 100 Ω; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; Fig. 12	200	1000	-	V/µs
		$V_{DM}$ = 536 V; T <sub>j</sub> = 125 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit; Fig. 12	50	130	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$ I_{TM} = 40 \text{ A};  V_{\text{D}} = 500  \text{V};  I_{\text{G}} = 0.1  \text{A}; \\ dI_{\text{G}}/dt = 5  \text{A}/\mu\text{s};  T_{\text{J}} = 25 ^{\circ}\text{C} $	-	2	-	μs
t <sub>q</sub>	commutated turn-off time		-	70	-	μs



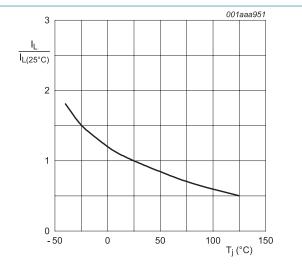
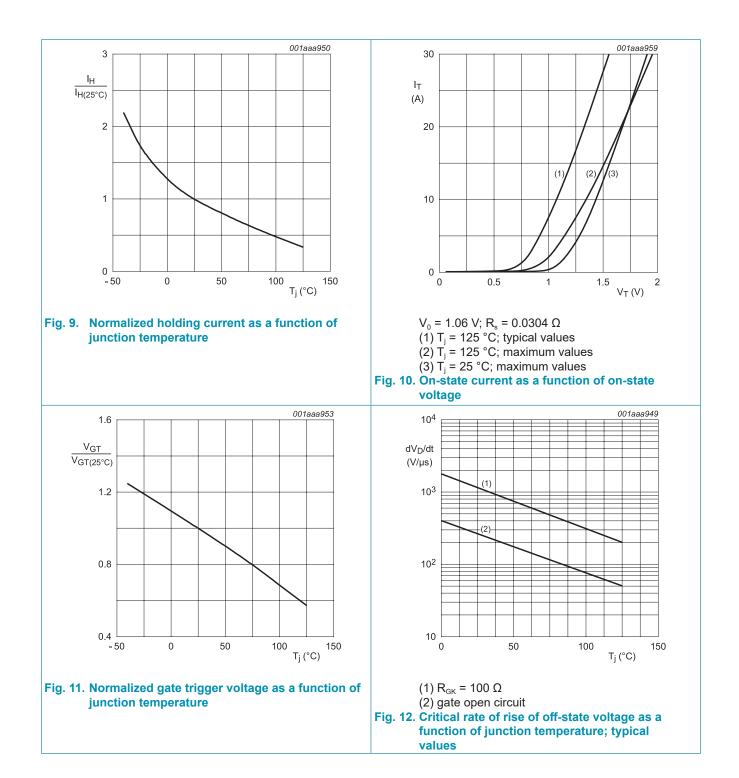
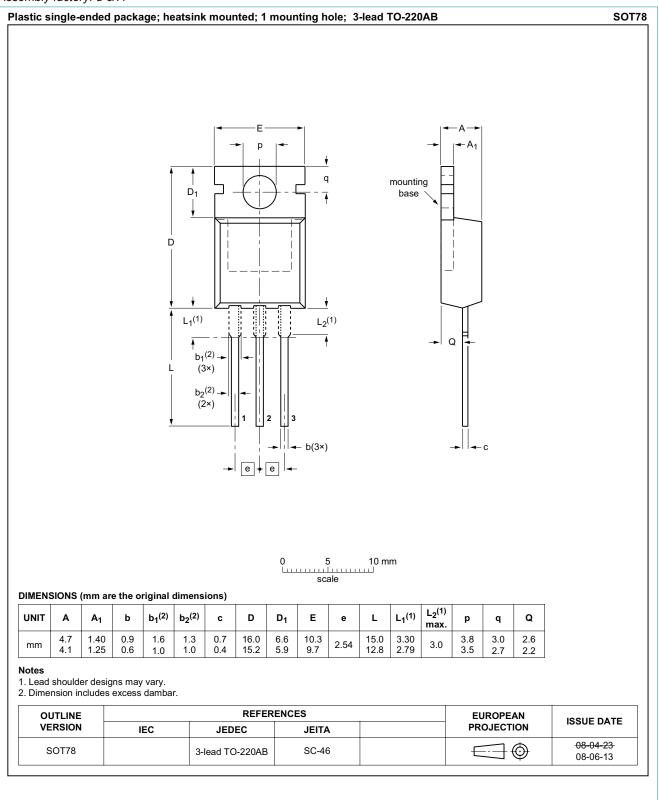


Fig. 8. Normalized latching current as a function of junction temperature



## **11. Package outline**

## Assembly factory: d & A



# 12. Legal information

## Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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